



DMN2990UFA

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
20V	$0.99\Omega @ V_{GS} = 4.5V$	510mA
	1.2Ω @ V _{GS} = 2.5V	470mA
	1.8Ω @ V _{GS} = 1.8V	380mA
	2.4Ω @ V _{GS} = 1.5V	330mA

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch

20V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low Package Profile, 0.4mm Maximum Package height
- 0.48mm² package footprint, 16 times smaller than SOT23
- Low On-Resistance
- Very low Gate Threshold Voltage, 1.0V max
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

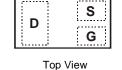
Mechanical Data

- Case: X2-DFN0806-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.001 grams (approximate)

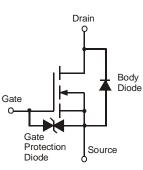




Bottom View



Package Pin Configuration



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2990UFA-7B	X2-DFN0806-3	10K/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

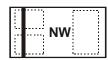
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

DMN2990UFA-7B



NW = Product Type Marking Code

Top View Bar Denotes Gate and Source Side



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	20	V		
Gate-Source Voltage	V _{GSS}	±8	V		
Continuous Drain Current (Note 5) V _{GS} = 4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	۱ _D	510 410	mA
	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	610 490	mA
Continuous Drain Current (Note 5) \/ 1.0\/	Steady State	T _A = +25°C T _A = 70°C	۱ _D	380 300	mA
Continuous Drain Current (Note 5) V_{GS} = 1.8V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	450 360	mA
Pulsed Drain Current (Note 6)			I _{DM}	800	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	Steady state	PD	400	mW
Thermal Resistance. Junction to Ambient (Note 5)	Steady state	P	310	°C/W
mermar Resistance, Junction to Ambient (Note 5)	t<10s	R ₀ JA	220	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zara Cata Valtaga Drain Current @T 125°C	I _{DSS}		_	100	nA	$V_{DS} = 16V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current $@T_C = +25^{\circ}C$		_	_	50		$V_{DS} = 5V, V_{GS} = 0V$	
Gate-Source Leakage		_	_	±100	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	0.4	_	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		_	0.60	0.99		$V_{GS} = 4.5V, I_D = 100mA$	
		_	0.75	1.2		$V_{GS} = 2.5V, I_D = 50mA$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	0.90	1.8	Ω	$V_{GS} = 1.8V, I_D = 20mA$	
		—	1.2	2.4		$V_{GS} = 1.5V, I_D = 10mA$	
		_	2.0			$V_{GS} = 1.2V, I_D = 1mA$	
Forward Transfer Admittance	Y _{fs}	180	_		mS	$V_{DS} = 10V, I_D = 400mA$	
Diode Forward Voltage		-	0.6	1.0	V	$V_{GS} = 0V, I_{S} = 150mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	27.6	55.2	pF		
Output Capacitance		_	4.0	8.0	pF	−V _{DS} = 16V, V _{GS} = 0V, −f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	2.8	5.6	pF		
Total Gate Charge	Qg	—	0.5		nC		
Gate-Source Charge		—	0.07		nC	$V_{GS} = 4.5V, V_{DS} = 10V,$	
Gate-Drain Charge	Q _{gd}	—	0.07	—	nC	$-I_D = 250 \text{mA}$	
Turn-On Delay Time	t _{D(on)}	—	4.0	—	ns		
Turn-On Rise Time Turn-Off Delay Time		_	3.3	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$	
		_	19.0	_	ns	$R_L = 47\Omega, R_G = 10\Omega,$	
Turn-Off Fall Time	t _f	_	6.4		ns	$I_D = 200 \text{mA}$	

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

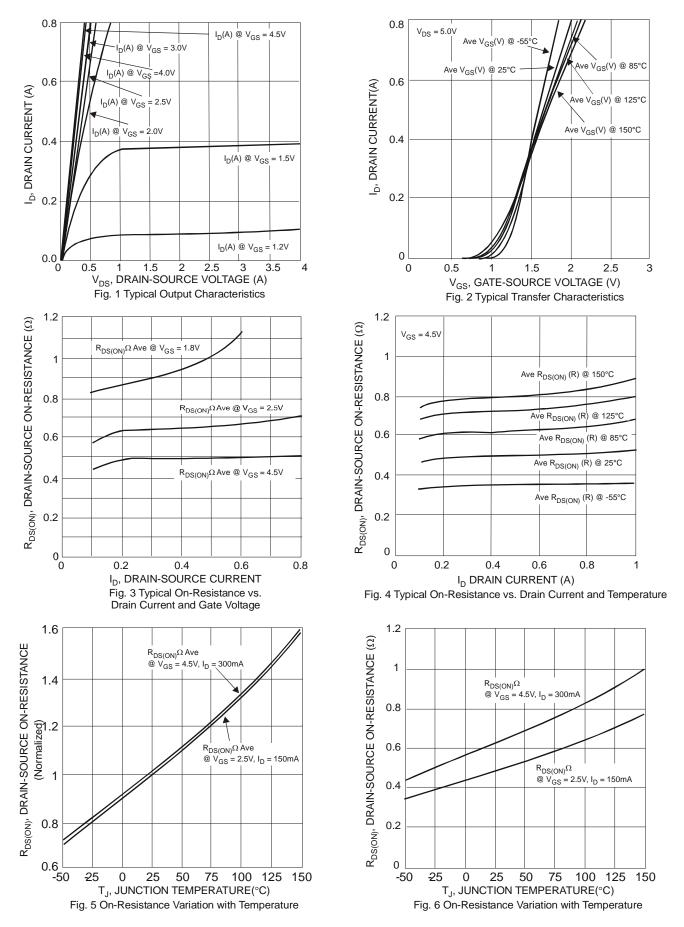
6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

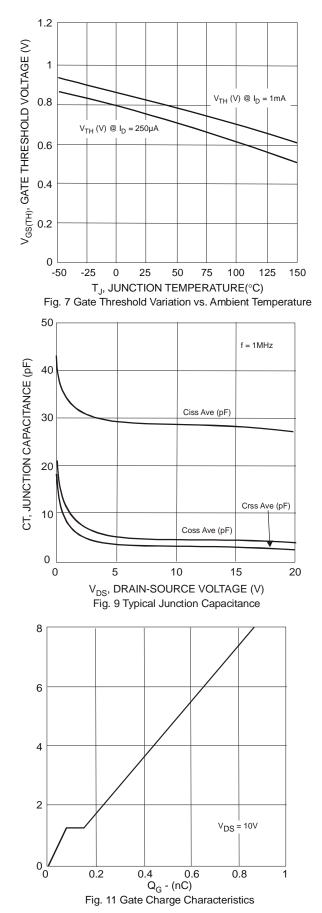


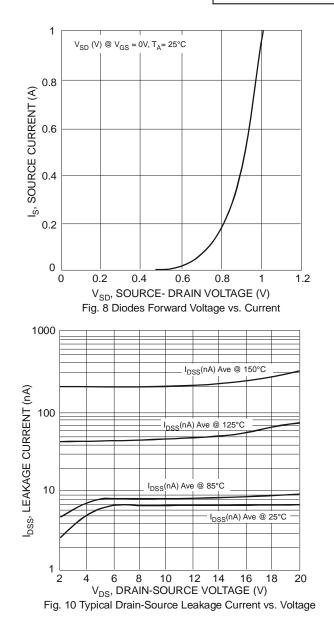
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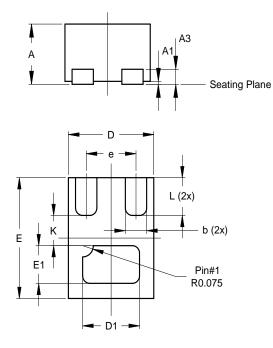






Package Outline Dimensions

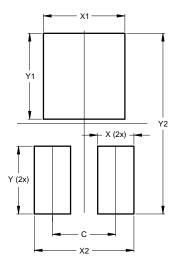
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X2-DFN0806-3						
Dim	Min	Тур				
Α	0.375	0.40	0.39			
A1	0	0.05	0.02			
A3	-	-	0.10			
b	0.10	0.20	0.15			
D	0.55	0.65	0.60			
D1	0.35	0.45	0.40			
Е	0.75	0.85	0.80			
E1	0.20	0.30	0.25			
e	-	-	0.35			
κ	-	-	0.20			
L	0.20	0.30	0.25			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.350
Х	0.200
X1	0.450
X2	0.550
Y	0.375
Y1	0.475
Y2	1.000



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